



## Axial lead diode

### Schottky barrier rectifiers diodes

**SB 1820 ... SB 1840**

**Forward Current: 18 A**

**Reverse Voltage: 20 to 40 V**

#### Features

- Max. solder temperature: 260 °C
- Plastic material has UL classification 94V-0

#### Mechanical Data

- Plastic case: 8 x 7,5 [mm]
- Weight approx.: 1,5 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 500 pieces per ammo or 1000 pieces per reel

- 1) Valid, if leads are kept at  $T_A$  at a distance of 10 mm from case
- 2)  $I_F = 5 \text{ A}$ ,  $T_j = 25 \text{ °C}$
- 3)  $T_A = 25 \text{ °C}$
- 4) Thermal resistance from junction to lead/terminal at a distance 0 mm from case
- 5) Max. junction temperature  $T_j \leq 200 \text{ °C}$  in bypass mode / DC forward mode

Type	Repetitive peak reverse voltage $V_{RRM}$ V	Surge peak reverse voltage $V_{RSM}$ V	Max. reverse recovery time $I_F = -A$ $I_R = -A$ $I_{RR} = -A$ $t_{rr}$ ns	Max. forward voltage $V_F^{(2)}$
SB 1820	20	20	-	0,39
SB 1830	30	30	-	0,39
SB 1840	40	40	-	0,39

Absolute Maximum Ratings		$T_A = 25 \text{ °C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
$I_{FAV}$	Max. averaged fwd. current, R-load, $T_A = 50 \text{ °C}^{(1)}$	18	A
$I_{FRM}$	Repetitive peak forward current $f > 15 \text{ Hz}^{(1)}$	70	A
$I_{FSM}$	Peak forward surge current Hz half sinus-wave $^{(3)}$	450	A
$i^2t$	Rating for fusing, $t < 10 \text{ ms}^{(3)}$	1020	A <sup>2</sup> s
$R_{thA}$	Max. thermal resistance junction to ambient $^{(1)}$		K/W
$R_{thL}$	Max. thermal resistance junction to terminals $^{(4)}$	3	K/W
$T_j$	Operating junction temperature	- 50 ... + 150 ( $T_j \leq 200 \text{ °C}$ in bypass mode $^{(5)}$ )	°C
$T_s$	Storage temperature	- 50 ... + 175	°C

Characteristics		$T_A = 25 \text{ °C}$ , unless otherwise specified	
Symbol	Conditions	Values	Units
$I_R$	Maximum leakage current, $T_j = 25 \text{ °C}$ ; $V_R = V_{RRM}$	<500	µA
	$T_j = 100 \text{ °C}$ ; $V_R = V_{RRM}$	30 (typ.)	mA
$C_j$	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
$Q_{rr}$	Reverse recovery charge ( $U_R = V$ ; $I_F = A$ ; $dI_F/dt = A/ms$ )	-	µC
$E_{RSM}$	Non repetitive peak reverse avalanche energy ( $I_R = mA$ ; $T_j = \text{°C}$ ; inductive load switched off)	-	mJ



